Adopted Levels

Type Author Citation Literature Cutoff Date
Full Evaluation Balraj Singh ENSDF 20-Jul-2015

 $Q(\beta^{-})=10400 \text{ SY}; S(n)=5210 \text{ SY}; S(p)=13390 \text{ SY}; Q(\alpha)=-9460 \text{ SY}$ 2012Wa38

 $\Delta Q(\beta^{-})=210$, $\Delta S(n)=220$, $\Delta S(p)=360$, $\Delta Q(\alpha)=360$ (2012Wa38).

 $Q(\beta^- n) = 6240\ 200,\ S(2n) = 9240\ 200,\ S(2p) = 29980\ 450\ (syst, 2012Wa38).$

1994Be24, 1998Do08: Produced from ²⁰⁸Pb(U,f) E=750 MeV/nucleon. Identified with on-line fragment separator at GSI; time of flight and energy loss measurements, no half-life measurement.

- 2006Mo07: ⁹Be(¹³⁶Xe,X),E=121.8 MeV/nucleon. The A1900 fragment separator at NSCL-MSU facility was used to separate nuclei of interest. The secondary beam was implanted into β-decay arrangement consisting of Si(PIN) detectors and Si strip detectors (DSSD) and single-sided Si strip detectors (SSSD). Implantation and decay events were time stamped and correlated. Measured half-life from ion-β correlated spectrum.
- 2008Be33: ¹¹⁵Tc produced in ⁹Be(¹³⁶Xe,X),E=1 GeV/nucleon, measured production σ at GSI 2011Ni01: ¹¹⁵Tc produced in Be(²³⁸U,F),E=345 MeV/nucleon, the beam produced by the cascade operation of the RBIF complex of accelerators at RIKEN. Target=550 mg/cm². Identification of ¹¹⁵Tc made on the basis of magnetic rigidity, time-of-flight and energy loss. The separated nuclei were implanted in a nine-layer double-sided silicon-strip detector (DSSSD). Correlations were recorded between the heavy ions and β rays. The half-life of ¹¹⁵Tc isotope was measured from the correlated ion-β decay curves and maximum likelihood analysis technique. In the analysis of the decay curve, β-detection efficiency, background rate, daughter and granddaughter (including those populated in delayed neutron decays) half-lives, and β-delayed neutron emission probabilities were considered. Comparison of measured half-lives with FRDM+QRPA and KTUY+GT2 calculations.
- 2015Lo04: ¹¹⁵Tc nuclide produced at RIBF-RIKEN facility in ⁹Be(²³⁸U,F) reaction at E=345 MeV/nucleon with an average intensity of 6×10¹⁰ ions/s. Identification of ¹¹⁵Tc was made by determining atomic Z and mass-to-charge ratio A/Q, where Q=charge state of the ions. The selectivity of ions was based on magnetic rigidity, time-of-flight and energy loss. The separated nuclei were implanted at a rate of 50 ions/s in a stack of eight double-sided silicon-strip detector (WAS3ABi), surrounded by EURICA array of 84 HPGe detectors. Correlations were recorded between the implanted ions and β rays. The half-life of ¹¹⁵Tc isotope was measured from the correlated ion-β decay curves and maximum likelihood analysis technique as described in 2014Xu07. Comparison of measured half-lives with FRDM+QRPA, KTUY+GT2 and DF3+CQRPA theoretical calculations. 2013Fa05: theoretical calculation of T_{1/2} and %β⁻n.

¹¹⁵Tc Levels

E(level) $T_{1/2}$

Comments

Theoretical $T_{1/2}$ =34.5 ms, $\%\beta^-$ n=25.6 (2003Mo09).

 $\%\beta^{-}=100; \%\beta^{-}n=?$

E(level): measured half-life is assumed to correspond to the ground state of ¹¹⁵Tc.

 J^{π} : 3/2⁻ (syst,2012Au07), 5/2⁺ from theoretical considerations (1997Mo25).

 $T_{1/2}$: measured by 2015Lo04 from (implanted ions) β correlated curves in time and position using maximum likelihood method. Others: 83 ms +20-13 (2011Ni01, from the analysis of (ion) β -correlated decay curve); 73 ms +32-22 (2006Mo07, from ion- β correlated decay curve). See 2015Lo04 for comparison of their experimental value with theoretical values.